

Cervoz Industrial Embedded Module

Half Size mSATA

Titan Series (TLC)

T350 Family

Product Datasheet



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Revision History

Date	Revision	Description
2020.11.02	1.0	First Released

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1. Product Overview

1.1 Introduction

Cervoz Industrial Half Size mSATA (MO-300B) Embedded Module T350 family is a Solid State Flash Disk product that is in compliance with the mSATA and SATA III standards. Half Size mSATA T350 family fits in any mSATA sockets in a PC or motherboard; it can be used for both booting and storage purposes.

T350 family uses SSD grade quality 3D NAND flash memory from the industry leading manufacturer Kioxia (Toshiba). Cervoz's firmware builds in a powerful ECC algorithm call Low-Density Parity Check (LDPC) decoding to improve data reliability. This product includes various capacities to choose from.

T350 family offers outstanding performance and reliability; the product family is a good cost-effective solution for semi-industrial and high-capacity storage applications.

1.2 Feature

- Compliant with SATA III 6.0Gb/s
- 3D TLC NAND flash memory
- Capacity: 64GB ~ 512GB
- End-to-End data protection
- SLC write cache technology
- Operating as boot disk
- Product includes Standard Temperature range & Wide Temperature range
- Static and dynamic wear leveling
- Bad block management
- S.M.A.R.T. & TRIM command

1.3 Product Appearance & Models

Cervoz Industrial Half Size mSATA Module T350



T350 Family Standard Temp. (0°C ~ 70°C) Model No.	T350 Family Wide Temp. (-40°C ~ 85°C) Model No.	Capacity
CIE-HMT350TLF064GS	CIE-HMT350TLF064GW	64GB
CIE-HMT350TLF128GS	CIE-HMT350TLF128GW	128GB
CIE-HMT350TMF256GS	CIE-HMT350TMF256GW	256GB
CIE-HMT350TNF512GS	CIE-HMT350TNF512GW	512GB

Please Note:

Since certain storage capacity has to be reserved for firmware and controller management purposes; the physical capacity of the SATA flash module will be approximately 92.5% of the indicated capacity. If you need to install an image that has the exact (or close to) the indicated size of the flash module, please choose your flash module with a greater capacity.

2. Product Specifications

2.1 General Specifications

Form Factor	Half Size mSATA (MO-300B)
Interface	SATA III 6.0Gb/s (backward compatible to 3.0Gb/s, 1.5Gb/s)
Connector	mSATA
NAND Flash Type	3D TLC
Capacity	64GB/128GB/256GB/512GB
Sequential Read	up to 540MB/s
Sequential Write	up to 470MB/s
ECC Scheme	Applies the LDPC (Low Density Parity Check) of ECC algorithm
MTBF	2,000,000 hours
TeraByte Written (TBW)	64GB : 63 128GB : 125 256GB : 250 512GB : 500
Low Power Management	DIPM/HIPM mode
Supply Voltage	+3.3V DC +/-5%
Power Consumption	Active mode: < 1700mW Idle mode: < 325mW
Dimension (LxWxH)	26.80*29.85*4.00mm

2.2 Performance

The performance was measured with below PC configuration:

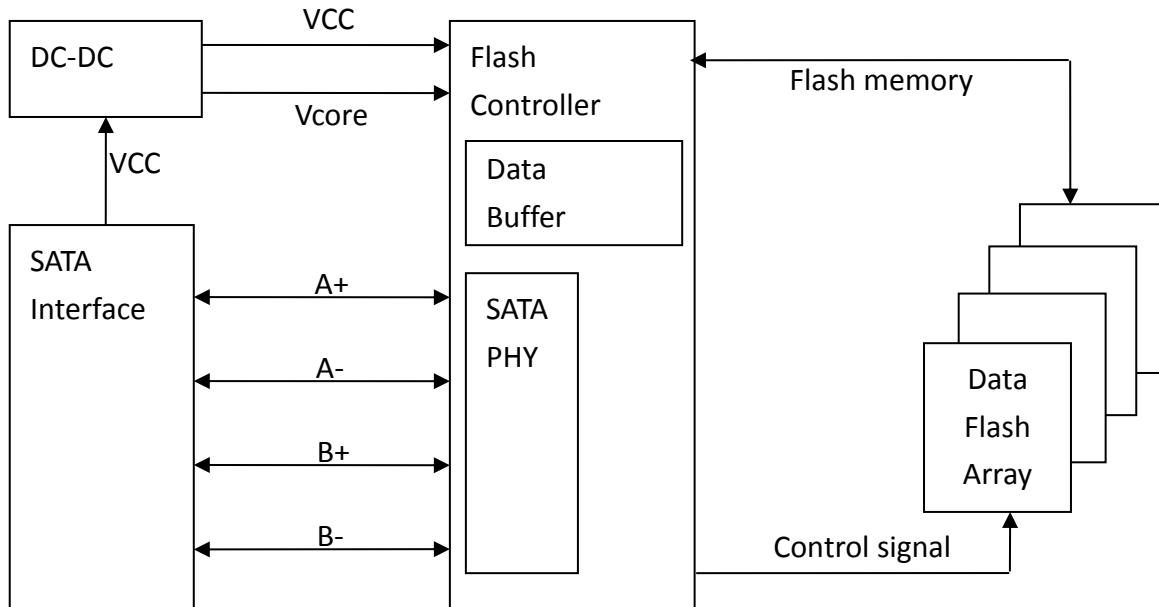
- Platform: ASUS Z97-A (Intel Z97)
- RAM: Cervoz CIR-S3DUSK1604G(DDR3 4G 1600MHz)
- Operation Systems: Windows 7
- Testing Utility: Crystal Disk Mark v5.1.0
- SATAIII port (6.0 Gb/s) performance

Capacity	64GB	128GB	256GB	512GB
Sequential Read (max.)	540MB/s	540MB/s	540MB/s	540MB/s
Sequential Write (max.)	240MB/s	420MB/s	460MB/s	470MB/s
4KB Random Read (QD32)	130MB/s	250MB/s	270MB/s	270MB/s
4KB Random Write (QD32)	240MB/s	230MB/s	260MB/s	260MB/s

Actual performance may vary depending on use conditions and environment

2.3 Electronic Specifications

2.3.1 Block Diagram



2.3.2 Pin Assignment



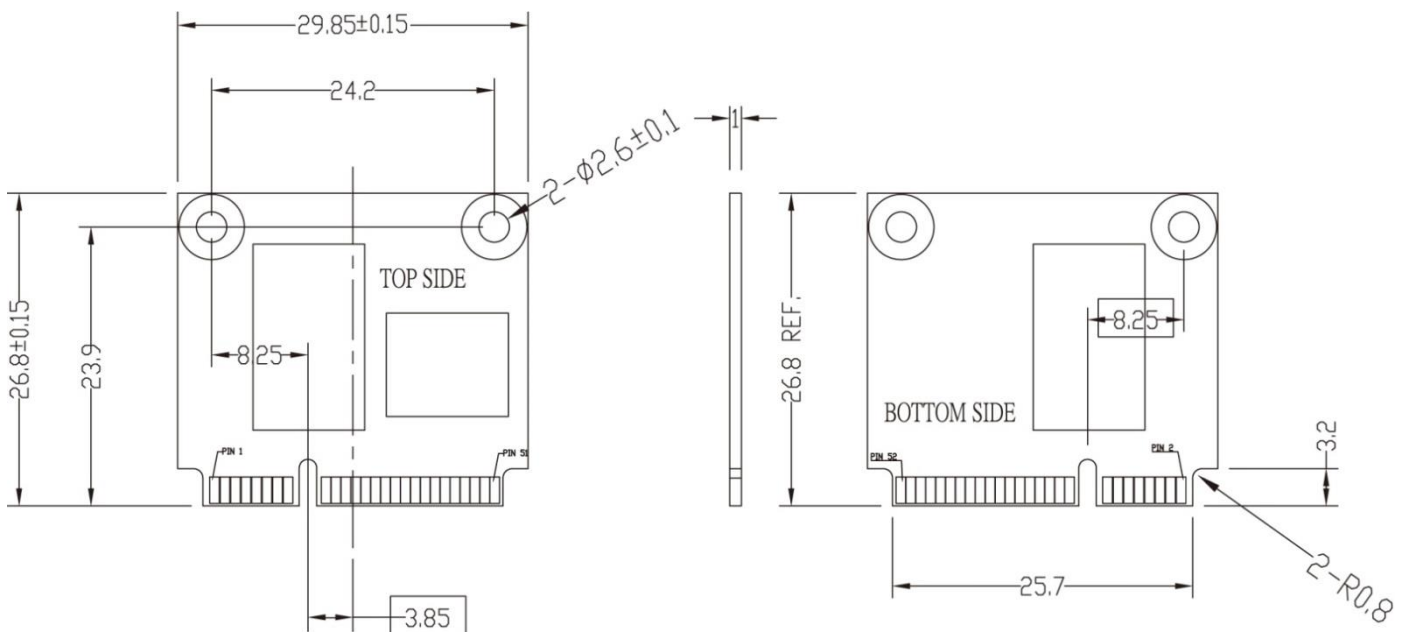
Pin #	Pin Description	Signal Name	Pin #	Pin Description	Signal Name
1	Not Used	NC	27	Ground	GND
2	3.3V power in	+3.3V	28	Not Used	NC
3	Not Used	NC	29	Ground	GND
4	Ground	GND	30	Not Used	NC
5	Not Used	NC	31	SATA Rxn	-A – RX-
6	Not Used	NC	32	Not Used	NC
7	Not Used	NC	33	SATA Rxp	+A – RX-
8	Not Used	NC	34	Ground	GND
9	Ground	GND	35	Ground	GND
10	Not Used	NC	36	Not Used	NC
11	Not Used	NC	37	Ground	GND
12	Not Used	NC	38	Not Used	NC
13	Not Used	NC	39	3.3V power in	+3.3V
14	Not Used	NC	40	Ground	GND
15	Ground	GND	41	3.3V power in	+3.3V
16	Not Used	NC	42	Not Used	NC
17	Not Used	NC	43	Not Used	NC
18	Ground	GND	44	Enter/Exit Device Sleep	DEVSLP
19	Not Used	NC	45	Not Used	NC
20	Not Used	NC	46	Not Used	NC
21	Ground	GND	47	Not Used	NC
22	Not Used	NC	48	Not Used	NC
23	SATA Txp	+B - TX+	49	Device Activity Signal	DAS
24	3.3V power in	+3.3V	50	Ground	GND
25	SATA Txn	-B - TX-	51	Default connect to GND	GND
26	Ground	GND	52	3.3V power in	+3.3V

2.4 Environmental Specifications

Type		Value
Temperature	Standard Temperature Operating:	0°C~70°C
	Standard Temperature Storage:	-40°C~85°C
	Wide Temperature Operating:	-40°C~85°C
	Wide Temperature Storage:	-50°C~95°C
Humidity	Operating & Storage	10~95%, Non-Condensing
Vibration	Non-Operating	20G, 10Hz~2000Hz
Shock	Non-Operating	1500G, 0.5ms

2.5 Mechanical Specifications

Type	Value
Form Factor	Half Size mSATA (MO-300B)
Length	26.80mm +/-0.15mm
Width	29.85mm +/-0.15mm
Thickness	4.00mm +/-0.15mm



3. Supported Command

3.1 List of Command Sets

Code	Description	Code	Description
00h	NOP	B0h, D1h	SMART READ DATA ATTRIBUTE THRESHOLD
06h	Data Set Management	B0h, D2h	SMART ENABLE/DISABLE ATTRIBUTE AUTOSAVE
10h	Recalibrate	B0h, D3h	SMART SAVE ATTRIBUTE VALUES
20h	Read Sectors	B0h, D4h	SMART EXECUTE OFF-LINE IMMEDIATE
21h	Read Sectors without Retry	B0h, D5h	SMART READ LOG
24h	Read Sectors EXT	B0h, D6h	SMART WRITE LOG
25h	Read DMA EXT	B0h, D8h	SMART ENABLE OPERATIONS
27h	Read Native Max Address EXT	B0h, D9h	SMART DISABLE OPERATIONS
29h	Read Multiple EXT	B0h, DAh	SMART RETURN STATUS
2Fh	Read Log EXT	B0h, DBh	SMART ENABLE/DISABLE AUTOMATIC OFF-LINE
30h	Write Sectors	B1h	DEVICE CONFIGURATION OVERLAY
31h	Write Sectors without Retry	B1h, C0h	DEVICE CONFIGURATION RESTORE
34h	Write Sectors EXT	B1h, C1h	DEVICE CONFIGURATION FREEZE LOCK
35h	Write DMA EXT	B1h, C2h	DEVICE CONFIGURATION IDENTIFY
37h	Set Native Max Address EXT	B1h, C3h	DEVICE CONFIGURATION SET
39h	Write Multiple EXT	B1h, C4h	DEVICE CONFIGURATION IDENTIFY DMA
3Dh	Write DMA FUA EXT	B1h, C5h	DEVICE CONFIGURATION SET DMA
3Fh	Write Long EXT	C4h	Read Multiple
40h	Read Verify Sectors	C5h	Write Multiple
41h	Read Verify Sectors without Retry	C6h	Set Multiple Mode
42h	Read Verify Sectors EXT	C8h	Read DMA
45h	Write Uncorrectable EXT	C9h	Read DMA without Retry
47h	Read Log DMA EXT	CAh	Write DMA
57h	Write Log DMA EXT	CBh	Write DMA without Retry
60h	Read FPDMA Queued	CEh	Write Multiple FUA EXT
61h	Write FPDMA Queued	E0h	Standby Immediate
70h	Seek	E1h	Idle Immediate
90h	Execute Device Diagnostic	E2h	Standby
91h	Initialize Device Parameters	E3h	Idle
92h	Download Microcode	E4h	Read Buffer
93h	Download Microcode DMA	E5h	Check Power Mode
B0h	SMART	E6h	Sleep
B0h, D0h	SMART READ DATA	E7h	Flush Cache

Code	Description	Code	Description
E8h	Write Buffer	Efh, 82h	Disable write cache
E9h	Read Buffer DMA	Efh, 85h	Disable advanced power management
EAh	Flush Cache EXT	Efh, 90h	Disable use of Serial ATA feature set
EBh	Write Buffer DMA	Efh, 90h, 02h	Disable DMA Setup FIS Auto-Activate optimization
ECh	Identify Device	Efh, 90h, 03h	Disable Device-initiated interface power state (DIPM) transitions
EFh	Set Features	Efh, 90h, 06h	Disable Software Settings Preservation (SSP)
Efh, 02h	Enable 8-bit PIO transfer mode	Efh, 90h, 07h	Disable Device Automatic Partial to Slumber transitions
Efh, 03h	Set transfer mode based on value in Count field	Efh, 90h, 09h	Disable Device Sleep
Efh, 05h	Enable advanced power management	Efh, AAh	Enable read look-ahead feature
Efh, 10h	Enable use of Serial ATA feature	Efh, CCh	Enable reverting to power-on defaults
Efh, 10h, 02h	Enable DMA Setup FIS Auto-Activate optimization	F1h	Security Set Password
Efh, 10h, 03h	Enable Device-initiated interface power state (DIPM) transitions	F2h	Security Unlock
Efh, 10h, 06h	Enable Software Settings Preservation (SSP)	F3h	Security Erase Prepare
Efh, 10h, 07h	Enable Device Automatic Partial to Slumber transitions	F4h	Security Erase Unit
Efh, 10h, 09h	Enable Device Sleep	F5h	Security Freeze Lock
Efh, 55h	Disable read look-ahead feature	F6h	Security Disable Password
Efh, 66h	Disable reverting to power-on defaults	F8h	Read Native Max Address

4. Part No. Decoder

4.1 Part No. Decoder

1	-	2	3	4	5	6	7	8	9
Product Line	-	Form Factor	Product Series	Cervoz Family Code (Bus / Internal Control)	Flash Brand	Flash Capacity	Flash Mode	Module Capacity	Operating Temp.
XXX	-	XX	X	XXX	X	X	X	XXXX	X

1. Product Line

CIS	Cervoz Industrial SSD
CIM	Cervoz Industrial Memory Card
CIE	Cervoz Industrial Embedded Module

2. Form Factor

2S	2.5" SATA
2P	2.5" PATA
CF	CompactFlash
CA	CFast
MS	mSATA
HM	Half Size mSATA
HS	Half Slim
M4	M.2 2242
M6	M.2 2260
M8	M.2 2280
0V	PATA Disk 40pin Vertical
4V	PATA Disk 44pin Vertical
4L	PATA Disk 44pin Horizontal Left
7T	SATA Disk 7pin Vertical Tall
7L	SATA Disk 7pin Horizontal Left
7R	SATA Disk 7pin Horizontal Right

3. Product Series

S	Supreme Series (SLC)
R	Reliance Series (RO-MLC)
M	Momentum Series (MLC)
T	Titan Series (TLC)

4. Cervoz Family Code

Bus and Internal Control for Cervoz Product Families

5. Flash Brand

M	Micron
T	Kioxia (Toshiba)

6. Flash Capacity

A	256Mb
B	512Mb
C	1Gb
D	2Gb
E	4Gb
F	8Gb
G	16Gb
H	32Gb
I	64Gb
J	128Gb
K	256Gb
L	512Gb
M	1Tb
N	2Tb
O	4Tb

7. Flash Mode

Internal Control for Flash Mode

8. Module Capacity

128M	128MB
256M	256MB
512M	512MB
001G	1GB
002G	2GB
004G	4GB
008G	8GB
016G	16GB
032G	32GB
064G	64GB
128G	128GB
256G	256GB
512G	512GB
001T	1TB
002T	2TB

9. Operating Temperature

S	Standard Grade (0~ +70°C)
W	Wide Temperature Grade (-40 ~ +85°C)